NSN 5961-01-449-1301

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End Application:

Oidt e/i fscm 03950

Internal Configuration:

Junction contact

Features Provided:

Hermetically sealed case and high power

Semiconductor Material:

Silicon

Special Features:

Next higher assembly: g111250; junction pattern arrangement: npn

Special Test Features:

Selected turn-off time

Test Data Document:

81349-mil-s-19500/371a specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 49956-g393167 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Shelf Life:**

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0